Low-ohmic dual single-pole double-throw analog switchRev. 5 — 18 June 2012Product data sheet

### 1. General description

The NX3L2267 is a dual low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. Each switch has a digital select input (nS), two independent inputs/outputs (nY0 and nY1) and a common input/output (nZ).

Schmitt trigger action at the digital inputs makes the circuit tolerant to slower input rise and fall times. Low threshold digital inputs allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current I<sub>CC</sub>. This makes it possible for the NX3L2267 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation. The NX3L2267 allows signals with amplitude up to V<sub>CC</sub> to be transmitted from nZ to nY0 or nY1, or from nY0 or nY1 to nZ. Its low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

## 2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
  - 1.65 Ω (typical) at V<sub>CC</sub> = 1.4 V
  - 0.95  $\Omega$  (typical) at V<sub>CC</sub> = 1.65 V
  - 0.55  $\Omega$  (typical) at V<sub>CC</sub> = 2.3 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 2.7 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 7500 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM AEC-Q100-011 revision B exceeds 1000 V
  - IEC61000-4-2 contact discharge exceeds 6000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at V<sub>CC</sub> = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V<sub>CC</sub>
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



## 3. Applications

- Cell phone
- PDA
- Portable media player

## 4. Ordering information

#### Table 1. Ordering information

Type number	Package	Package							
	Temperature range	Name	Description	Version					
NX3L2267GM	–40 °C to +125 °C	XQFN10	plastic extremely thin quad flatpackage; no leads; 10 terminals; body $2 \times 1.55 \times 0.5$ mm	SOT1049-3					
NX3L2267GU	–40 °C to +125 °C	XQFN10	plastic, extremely thin quad flat package; no leads; 10 terminals; body $1.40 \times 1.80 \times 0.50$ mm	SOT1160-1					

## 5. Marking

Table 2. Marking	
Type number	Marking code
NX3L2267GM	M67
NX3L2267GU	M7

## 6. Functional diagram



#### Low-ohmic dual single-pole double-throw analog switch

## 7. Pinning information

### 7.1 Pinning







Symbol	Pin		Description
	SOT1049-3	SOT1160-1	
1Y0	1	10	independent input or output
1Y1	2	1	independent input or output
2Y0	3	2	independent input or output
2Y1	4	3	independent input or output
GND	5	4	ground (0 V)
2Z	6	5	common output or input
2S	7	6	select input
1S	8	7	select input
1Z	9	8	common output or input
V <sub>CC</sub>	10	9	supply voltage

### 8. Functional description

#### Table 4.Function table<sup>[1]</sup>

Input nS	Channel on
L	nY0 = nZ
Н	nY1 = nZ

[1] H = HIGH voltage level; L = LOW voltage level.

## 9. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
VI	input voltage	select input nS	[1]	-0.5	+4.6	V
V <sub>SW</sub>	switch voltage		[2]	-0.5	$V_{CC} + 0.5$	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V		-50	-	mA
I <sub>SK</sub>	switch clamping current	$V_{\rm I}$ < –0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V		-	±50	mA
I <sub>SW</sub>	switch current	$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; source or sink current		-	±350	mA
		$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current		-	±500	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	<u>[3][4]</u>	-	250	mW
-						

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For XQFN10 (SOT1049-3) package: above 132 °C the value of P<sub>tot</sub> derates linearly with 14.1 mW/K.

[4] For XQFN10 (SOT1160-1) package: above 128 °C the value of Ptot derates linearly with 11.5 mW/K.

## **10. Recommended operating conditions**

#### Table 6. **Recommended operating conditions** Symbol Parameter Conditions Min Max supply voltage Vcc 1.4 4.3 Vı input voltage select input nS 0 4.3 <u>[1]</u> 0 V<sub>SW</sub> switch voltage switch input nY0 or nY1 V<sub>CC</sub> ambient temperature -40 +125 Tamb [2] \_ $\Delta t / \Delta V$ input transition rise and fall rate $V_{CC}$ = 1.4 V to 4.3 V 200

[1] To avoid sinking GND current from terminal nZ when switch current flows in terminal nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no GND current will flow from terminal nYn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to select input nS signal levels.

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NX3L2267

4 of 22

Unit

V

V

V

°C

ns/V

## **11. Static characteristics**

#### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	T,	<sub>amb</sub> = 25	°C	T <sub>amb</sub> = -40 °C to +125 °C			Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V <sub>IH</sub>	HIGH-level	$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	0.9	-	-	0.9	-	-	V
	input voltage	$V_{CC}$ = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V
		$V_{CC}$ = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	1.3	-	-	1.3	-	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	1.4	-	-	1.4	-	-	V
V <sub>IL</sub>	LOW-level	$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	-	0.3	-	0.3	0.3	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.5	-	0.5	0.4	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.5	-	0.5	0.5	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	0.6	-	0.6	0.6	V
I	input leakage current	select input nS; V <sub>I</sub> = GND to 4.3 V; V <sub>CC</sub> = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
I <sub>S(OFF)</sub>	S(OFF) OFF-state	nYn port; see <u>Figure 5</u>							
leakage	$V_{CC}$ = 1.4 V to 3.6 V	-	-	±5	-	±10	±100	nA	
	current	$V_{CC}$ = 3.6 V to 4.3 V	-	-	±10	-	±50	±200	nA
I <sub>S(ON)</sub>	ON-state	nZ port; see Figure 6							
	leakage	$V_{CC}$ = 1.4 V to 3.6 V	-	-	±5	-	±20	±200	nA
	current	$V_{CC}$ = 3.6 V to 4.3 V	-	-	±10	-	±50	±400	nA
I <sub>CC</sub>	supply current	$V_{I} = V_{CC}$ or GND; $V_{SW} = GND$ or $V_{CC}$							
		V <sub>CC</sub> = 3.6 V	-	-	100	-	300	3000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	500	5000	nA
$\Delta I_{CC}$	additional	$V_{SW}$ = GND or $V_{CC}$							
	supply current	$V_{I} = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	2.0	4.0	-	7	7	μA
		$V_{I} = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	0.35	0.7	-	1	1	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	7.0	10.0	-	15	15	μA
		V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 3.6 V	-	2.5	4.0	-	5	5	μΑ
		$V_{I} = 1.8 \text{ V}; V_{CC} = 2.5 \text{ V}$	-	50	200	-	300	500	nA
CI	input capacitance		-	1.0	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance	port nYn	-	35	-	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance	port nYn	-	135	-	-	-	-	pF

#### Low-ohmic dual single-pole double-throw analog switch

### 11.1 Test circuits





#### 11.2 ON resistance

#### Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 8 to Figure 14.

Symbol	Parameter	Conditions		–40 °C to +85 °C		–40 °C to	–40 °C to +125 °C	
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R <sub>ON(peak)</sub>	ON resistance (peak)	port nYn; V <sub>I</sub> = GND to V <sub>CC</sub> ; I <sub>SW</sub> = 100 mA; see Figure 7			'			
		$V_{CC} = 1.4 V$	-	1.65	3.7	-	4.1	Ω
		V <sub>CC</sub> = 1.65 V	-	0.95	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.50	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.50	0.75	-	0.9	Ω
0.1	ON resistance mismatch between channels	$V_I = GND \text{ to } V_{CC};$ [2] $I_{SW} = 100 \text{ mA}$						
		V <sub>CC</sub> = 1.4 V	-	0.20	0.35	-	0.35	Ω
		V <sub>CC</sub> = 1.65 V	-	0.20	0.25	-	0.30	Ω
		$V_{CC} = 2.3 V$	-	0.09	0.13	-	0.15	Ω
		$V_{CC} = 2.7 V$	-	0.09	0.125	-	0.15	Ω
		$V_{CC} = 4.3 V$	-	0.09	0.125	-	0.15	Ω
R <sub>ON(flat)</sub>	ON resistance (flatness)	port nYn; [3] $V_I = GND$ to $V_{CC}$ ; $I_{SW} = 100 \text{ mA}$						
		V <sub>CC</sub> = 1.4 V	-	1.05	3.35	-	3.65	Ω
		V <sub>CC</sub> = 1.65 V	-	0.55	1.25	-	1.35	Ω
		$V_{CC} = 2.3 V$	-	0.20	0.35	-	0.40	Ω
		$V_{CC} = 2.7 V$	-	0.18	0.35	-	0.40	Ω
		$V_{CC} = 4.3 V$	-	0.23	0.40	-	0.45	Ω

[1] Typical values are measured at  $T_{amb} = 25 \ ^{\circ}C$ .

[2] Measured at identical  $V_{CC}$ , temperature and input voltage.

[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

Low-ohmic dual single-pole double-throw analog switch



### 11.3 ON resistance test circuit and graphs

## NX3L2267

#### Low-ohmic dual single-pole double-throw analog switch



9 of 22

## NX3L2267

#### Low-ohmic dual single-pole double-throw analog switch



### 12. Dynamic characteristics

#### Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol	Parameter	Conditions	Ta	<sub>mb</sub> = 25	°C	T <sub>amb</sub> =	–40 °C to	+125 °C	Unit
			Min	Тур <u><sup>[1]</sup></u>	Мах	Min	Max (85 °C)	Max (125 °C)	
t <sub>en</sub> enable time		nS to nZ or nYn; see <u>Figure 15</u>							
		$V_{CC}$ = 1.4 V to 1.6 V	-	50	90	-	120	120	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	36	70	-	80	90	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	24	45	-	50	55	ns
		$V_{CC}$ = 2.7 V to 3.6 V	-	22	40	-	45	50	ns
		$V_{CC}$ = 3.6 V to 4.3 V	-	22	40	-	45	50	ns
t <sub>dis</sub>	disable time	nS to nZ or nYn; see <u>Figure 15</u>							
		$V_{CC}$ = 1.4 V to 1.6 V	-	32	70	-	80	90	ns
		$V_{CC}$ = 1.65 V to 1.95 V	-	20	55	-	60	65	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	12	25	-	30	35	ns
		$V_{CC}$ = 2.7 V to 3.6 V	-	10	20	-	25	30	ns
		$V_{CC}$ = 3.6 V to 4.3 V	-	10	20	-	25	30	ns

Symbol	Parameter	Conditions		T <sub>amb</sub> = 25 °C		T <sub>amb</sub> =	T <sub>amb</sub> = –40 °C to +125 °C			
				Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)	
t <sub>b-m</sub> break-before-make time	see Figure 16	[2]								
	$V_{CC}$ = 1.4 V to 1.6 V		-	19	-	9	-	-	ns	
		$V_{CC}$ = 1.65 V to 1.95 V		-	17	-	7	-	-	ns
		$V_{CC}$ = 2.3 V to 2.7 V		-	13	-	4	-	-	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		-	10	-	3	-	-	ns
		$V_{CC}$ = 3.6 V to 4.3 V		-	10	-	2	-	-	ns

#### Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

[1] Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

### 12.1 Waveform and test circuits



#### Table 10.Measurement points

Supply voltage	Input	Output
V <sub>cc</sub>	V <sub>M</sub>	V <sub>X</sub>
1.4 V to 4.3 V	0.5V <sub>CC</sub>	0.9V <sub>OH</sub>

## NX3L2267

#### Low-ohmic dual single-pole double-throw analog switch



Test data is given in Table 11.

Definitions test circuit:

R<sub>L</sub> = Load resistance.

 $C_{\mathsf{L}}$  = Load capacitance including jig and probe capacitance.

V<sub>EXT</sub> = External voltage for measuring switching times.

#### Fig 17. Test circuit for measuring switching times

#### Table 11. Test data

Supply voltage	Input		Load		
V <sub>cc</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	
1.4 V to 4.3 V	V <sub>CC</sub>	$\leq$ 2.5 ns	35 pF	50 Ω	

NX3L2267		
Product	data	sheet

### 12.2 Additional dynamic characteristics

#### Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \le 2.5$  ns.

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C			Unit	
				Min	Тур	Max	
THD	total harmonic distortion	$f_i = 20$ Hz to 20 kHz; $R_L = 32 \Omega$ ; see Figure 18	<u>[1]</u>		1		
		V <sub>CC</sub> = 1.4 V; V <sub>I</sub> = 1 V (p-p)		-	0.15	-	%
		V <sub>CC</sub> = 1.65 V; V <sub>I</sub> = 1.2 V (p-p)		-	0.10	-	%
		V <sub>CC</sub> = 2.3 V; V <sub>I</sub> = 1.5 V (p-p)		-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$		-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$		-	0.02	-	%
		$V_{CC}$ = 3.0 V; V <sub>I</sub> = 1 V (p-p); R <sub>L</sub> = 600 $\Omega$		-	0.01	-	%
f <sub>(-3dB)</sub>	-3 dB frequency	$R_L = 50 \Omega$ ; see Figure 19	[1]				
	response	port nYn; $V_{CC}$ = 1.4 V to 4.3 V		-	60	-	MHz
$\alpha_{\text{iso}}$	isolation (OFF-state)	$f_i = 100 \text{ kHz}; R_L = 50 \Omega; \text{ see } \frac{\text{Figure 20}}{100 \text{ kHz}}$	[1]				
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$		-	-90	-	dB
V <sub>ct</sub>	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$ ; $C_L = 50 \text{ pF}$ ; $R_L = 50 \Omega$ ; see Figure 21					
		$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$		-	0.21	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$		-	0.30	-	V
Xtalk	crosstalk	between switches; $f_i = 100 \text{ kHz}$ ; $R_L = 50 \Omega$ ; see <u>Figure 22</u>	<u>[1]</u>				
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$		-	-90	-	dB
Q <sub>inj</sub>	charge injection	$f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure } 23}{2}$					
		$V_{CC} = 1.5 V$		-	4	-	рС
		V <sub>CC</sub> = 1.8 V		-	6	-	рС
		$V_{CC} = 2.5 V$		-	16	-	рС
		$V_{CC} = 3.3 V$		-	24	-	рС
		$V_{CC} = 4.3 V$		-	37	-	рС

[1]  $f_i$  is biased at 0.5V<sub>CC</sub>.

#### Low-ohmic dual single-pole double-throw analog switch

### 12.3 Test circuits







#### Low-ohmic dual single-pole double-throw analog switch





## NX3L2267

#### Low-ohmic dual single-pole double-throw analog switch



16 of 22

## NX3L2267

Low-ohmic dual single-pole double-throw analog switch

## 13. Package outline



XQFN10: plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.55 x 2.00 x 0.50 mm

#### Fig 24. Package outline SOT1049-3 (XQFN10)

NX3L2267 **Product data sheet** 

Low-ohmic dual single-pole double-throw analog switch



XQFN10: plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.40 x 1.80 x 0.50 mm

#### Fig 25. Package outline SOT1160-1 (XQFN10)

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NX3L2267

## 14. Abbreviations

AcronymDescriptionCDMCharged Device ModelCMOSComplementary Metal-Oxide SemiconductorESDElectroStatic DischargeHBMHuman Body ModelMMMachine Model	Table 13. Abbreviations				
CMOSComplementary Metal-Oxide SemiconductorESDElectroStatic DischargeHBMHuman Body Model	Acronym	Description			
ESD     ElectroStatic Discharge       HBM     Human Body Model	CDM	Charged Device Model			
HBM Human Body Model	CMOS	Complementary Metal-Oxide Semiconductor			
	ESD	ElectroStatic Discharge			
MM Machine Model	HBM	Human Body Model			
	MM	Machine Model			

## **15. Revision history**

#### Table 14.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L2267 v.5	20120618	Product data sheet	-	NX3L2267 v.4
Modifications:	<ul> <li>Package ou</li> </ul>	utline drawing SOT1049-2 c	hanged to SOT1049-3 (	Figure 24).
NX3L2267 v.4	20111108	Product data sheet	-	NX3L2267 v.3
Modifications:	<ul> <li>Legal page</li> </ul>	s updated.		
NX3L2267 v.3	20101223	Product data sheet	-	NX3L2267 v.2
NX3L2267 v.2	20100713	Product data sheet	-	NX3L2267 v.1
NX3L2267 v.1	20091109	Product data sheet	-	-

### **16. Legal information**

#### 16.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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NX3L2267

#### Low-ohmic dual single-pole double-throw analog switch

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### **18. Contents**

1	General description	1
2	Features and benefits	1
3	Applications	2
4	Ordering information	2
5	Marking	2
6	Functional diagram	2
7	Pinning information	3
7.1	Pinning	3
7.2	Pin description	3
8	Functional description	4
9	Limiting values	4
10	Recommended operating conditions	4
11	Static characteristics	5
11.1	Test circuits	6
11.2	ON resistance	7
11.3	ON resistance test circuit and graphs	8
12	Dynamic characteristics 1	10
12.1		11
12.2	······································	13
12.3		14
13	Package outline 1	17
14	Abbreviations 1	9
15	Revision history 1	19
16	Legal information 2	20
16.1	Data sheet status 2	20
16.2	Definitions 2	20
16.3		20
16.4	Trademarks 2	21
17	Contact information 2	21
18	Contents	22

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